NSN 5961-01-080-2642

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View Online at https://aerobasegroup.com/nsn/5961-01-080-2642 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.345 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.8 base to emitter voltage, dc and 0.6 collector to emitter voltage, dc **Current Rating Per Characteristic:** 0.70 milliamperes zero-gate-voltage source current absolute and 5.00 milliamperes zero-gate-voltage source current major **Power Rating Per Characteristic:** 115.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Vbe and w are min ratings; lead length is 0.400 in. Min; junction pattern arrangement: npn **Test Data Document:** 24429-10-19655 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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